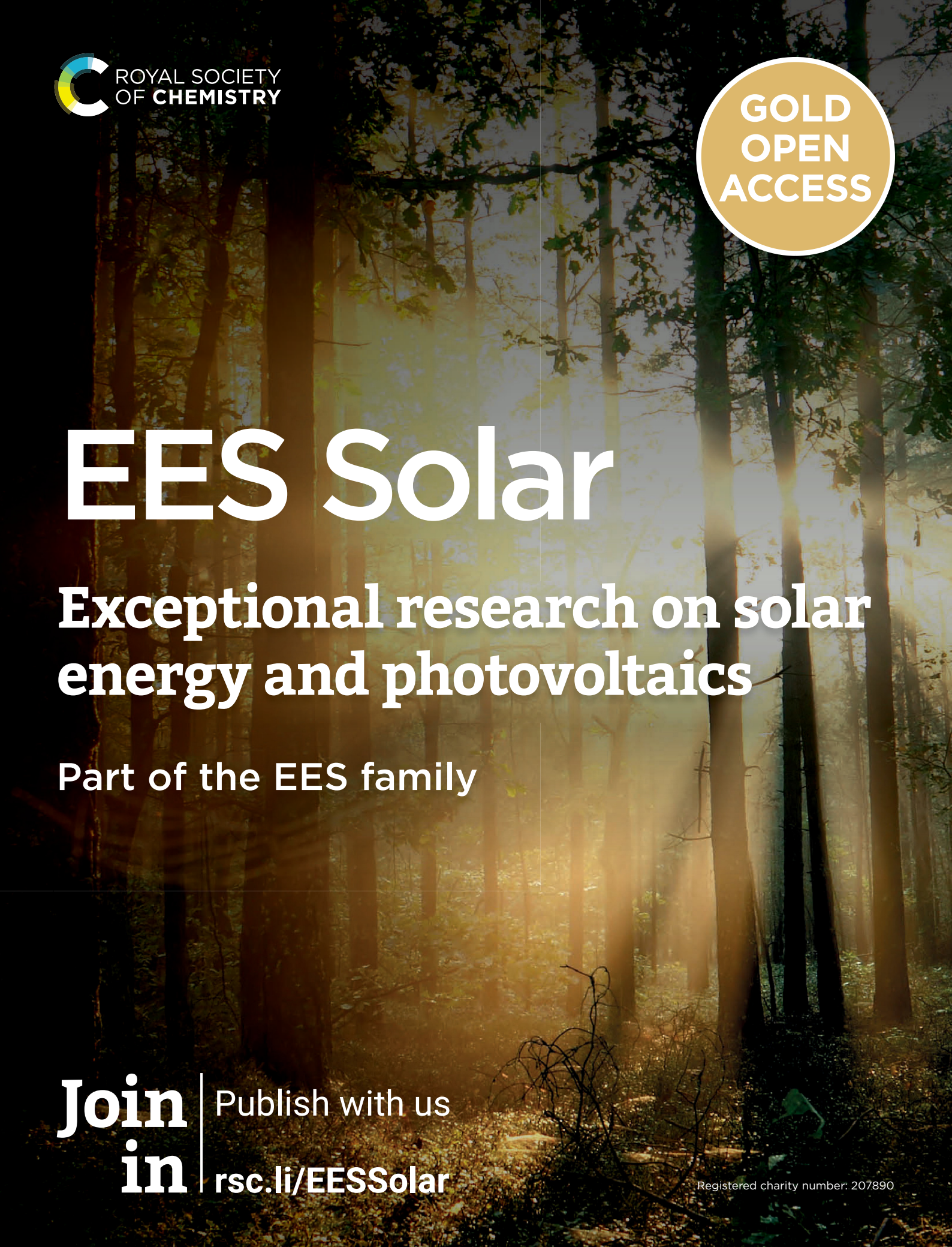
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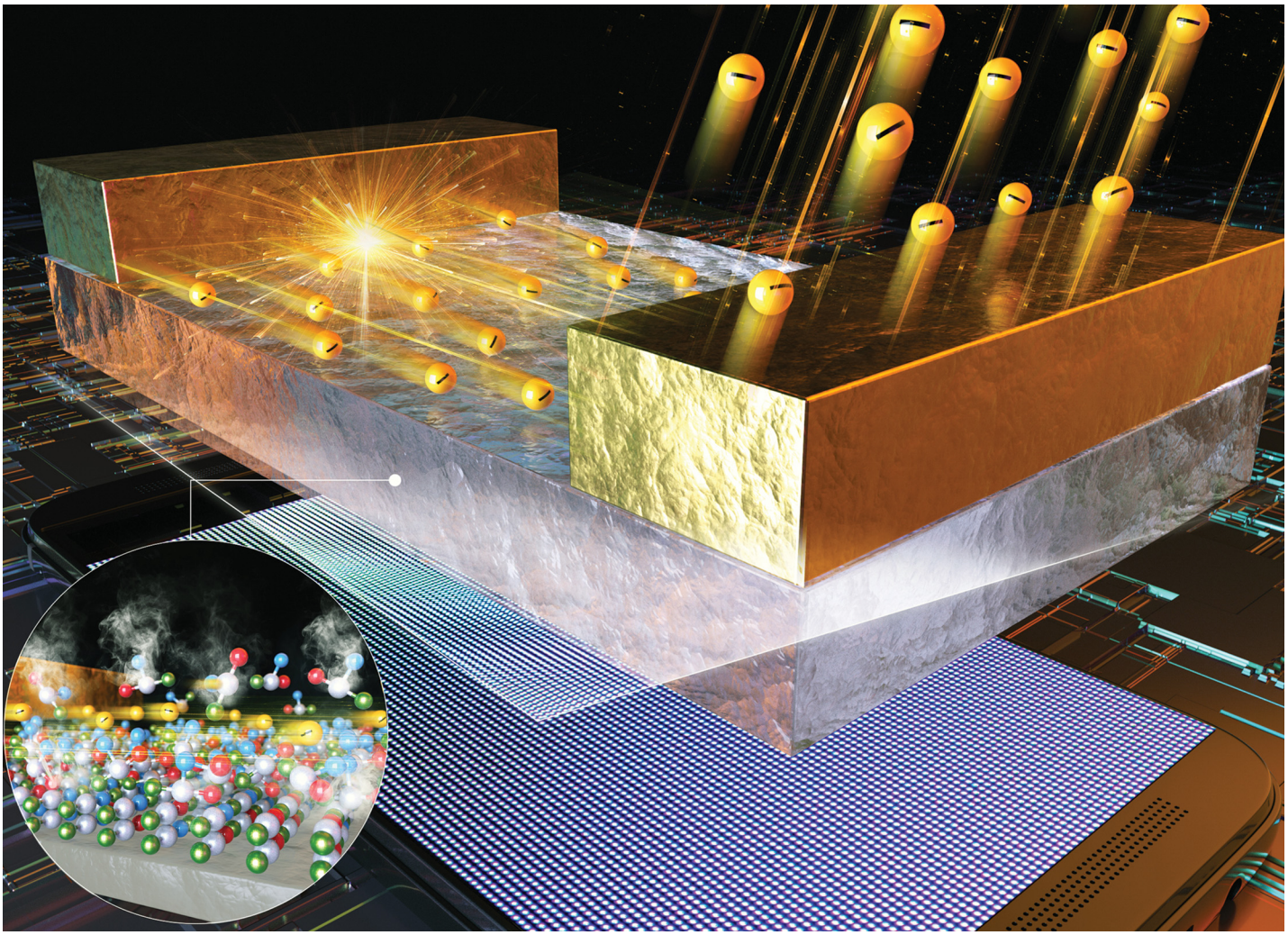
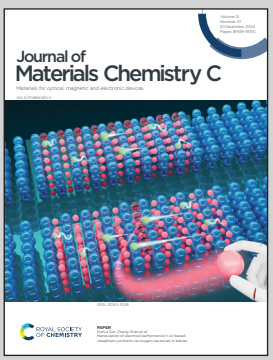


Showcasing research from Professor Tae-Jun Ha's laboratory, Department of Electronic Materials Engineering, Kwangwoon University, Seoul 01897, Republic of Korea.

Charge transport properties of high-mobility indium–gallium–zinc oxide thin-film transistors fabricated through atomic-layer deposition

Charge transport properties of high-mobility IGZO TFTs fabricated through ALD are investigated by steady-state DC and time-domain transient analyses and compared with those of IGZO TFTs fabricated through sol–gel coating and sputtering in the same device configuration for the first time.

As featured in:



See Yong-Hoon Kim, Yung-Bin Chung, Tae-Jun Ha *et al.*, *J. Mater. Chem. C*, 2024, **12**, 19071.

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